Examiner-Initiated Interview Summary	Application No.	Applicant(s)
	10/772,541	AGARWAL ET AL.
	Examiner	Art Unit
	Yewebdar T. Tadesse	1734
All Participants: Status of Application: After Final		
(1) <u>Yewebdar T. Tadesse</u> .	(3)	
(2) <u>Chen Liang</u> .	(4)	
Date of Interview: 8 March 2006	Time:	
Type of Interview: ☐ Telephonic ☐ Video Conference ☐ Personal (Copy given to: ☐ Applicant ☐ Applic Exhibit Shown or Demonstrated: ☐ Yes ☐ No If Yes, provide a brief description:	cant's representative)	
Part I.		
Rejection(s) discussed: None		
Claims discussed: 68, 69, 72, 75, 78 and 79		
Prior art documents discussed: None		
Part II.		
SUBSTANCE OF INTERVIEW DESCRIBING THE GENE examiner requested the attorney to clearly define the claimed in amendment)		
Part III.		
 It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview directly resulted in the allowance of the application. The examiner will provide a written summary of the substance of the interview in the Notice of Allowability. It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview did not result in resolution of all issues. A brief summary by the examiner appears in Part II above. 		
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Denul . C-6		
(Examiner/SPE Signature) (Applicar	nt/Applicant's Representative Si	gnature - if appropriate)

RECIPIENT:COMPANY:TELEPHONE:FACSIMILE:Examiner TadesseUSPTO571-272-1238571-273-1238

RE:

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Perkins Cole up and Affiliates

Attorney Docket No. 10829-8404U\$2

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF:

VISHNU K. AGARWAL AND

DINESH CHOPRA

EXAMINER: YEWEBDAR T. **TADESSE**

APPLICATION NO.:

10/772,541

1734

FILED:

FEBRUARY 5, 2004

ART UNIT: CONF. NO: 8900

For:

APPARATUSES FOR FORMING A

PLANARIZING PAD FOR **PLANARIZATION OF**

MICROELECTRONIC SUBSTRATES

Proposed Claim Amendment -For Discussion Purposes Only

Amendment to the Claims:

- 67. (Canceled).
- (Previously Presented) An apparatus for forming a planarizing pad for 68. mechanically and/or chemically-mechanically planarizing a microelectronic substrate. comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;
 - a vessel configured to contain a non-solid planarizing pad material;
 - at least one nozzle positioned over the support device and operatively coupled to the vessel and coupled to a source of compressed gas, the nozzle being configured to mix the planarizing pad material with the compressed gas to form discrete texture elements for disposing on the support material; and
 - a hopper positioned between the nozzle and the support device, the hopper having a first opening positioned proximate to the at least one nozzle for

[Proposed Claim Amendment 10829.8404.docProposed Claim Amendment.doc] -1-

receiving the discrete texture elements and a second opening proximate to the support material for disposing the received discrete texture elements on the support material when the support material is supported by the support device.

- 69. (Previously Presented) An apparatus for forming a planarizing pad for mechanically and/or chemically-mechanically planarizing a microelectronic substrate, comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;
 - a vessel configured to contain a non-solid planarizing pad material; and
 - at least one nozzle <u>positioned over the support device and operatively</u> coupled to the vessel and coupled to a source of compressed gas, the nozzle <u>being</u> configured to mix the planarizing pad material with the compressed gas to form discrete texture elements for disposing on the support material;
 - wherein the support material is elongated in a longitudinal direction and the at least one nozzle is the first of two nozzles coupled to the vessel, the second nozzle being offset in the longitudinal direction and in a lateral direction transverse to the longitudinal direction relative to the first nozzle.
 - 70. (Original) The apparatus of claim 69, further comprising: a manifold coupled to the vessel;
 - a first spraybar coupled to the manifold and extending over the support material in transverse direction when the support material is supported by the support device, the first nozzle being connected to the first spraybar; and
 - a second spraybar coupled to the manifold and spaced apart from the first spraybar in the longitudinal direction, the second spraybar extending transversely over the support material when the support material is supported by the support device, the second nozzle being connected to the second spraybar.

- 71. (Previously Presented) The apparatus of claim 69, further comprising a heating element positioned proximate to the support device and proximate to the pad support material when the pad support material is supported by the support device.
- 72. (Previously Presented) An apparatus for forming a planarizing pad for mechanically and/or chemically-mechanically planarizing a microelectronic substrate, comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;
 - a vessel configured to contain a non-solid planarizing pad material;
 - at least one nozzle positioned over the support device and operatively coupled to the vessel and coupled to a source of compressed gas, the nozzle being configured to mix the planarizing pad material with the compressed gas to form discrete texture elements for disposing on the support material; and a grate between the nozzle and the support device, the grate having a plurality of apertures sized to pass the discrete texture elements therethrough.
- 73. (Previously Presented) The apparatus of claim 69 wherein the first and second nozzles are positioned to spray the discrete texture elements directly onto the support material.
- 74. (Previously Presented) The apparatus of claim 68 wherein the vessel is a first vessel, and wherein the apparatus further comprises a second vessel positioned proximate to the second opening, the second vessel configured to contain the discrete texture elements and a film material.

- 75. (Currently Amended) An apparatus for forming a planarizing pad fdr mechanically and/or chemically-mechanically planarizing a microelectronic substrate, the apparatus comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;
 - a vessel for mixing a planarizing pad material;
 - a nozzle in fluid communication with the vessel and configured to form the planarizing pad material into discrete texture elements for disposing on the pad support material, wherein the pad support material is elongated in a longitudinal direction, and wherein the nozzle is positioned over the support device to spray the discrete texture elements at least partially in the longitudinal direction; and
 - a hopper positioned between the nozzle and the support device, the hopper having a first opening positioned proximate to the nozzle for receiving the discrete texture elements and a second opening proximate to the support material for disposing the received discrete texture elements on the support material when the support material is supported by the support device.
 - 76. (Canceled).
 - 77. (Canceled).
- 78. (Currently Amended) An apparatus for forming a planarizing pad for mechanically and/or chemically-mechanically planarizing a microelectronic substrate the apparatus comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;

- a vessel for mixing a planarizing pad material; and
- a nozzle in fluid communication with the vessel and configured to form the planarizing pad material into discrete texture elements for disposing on the support material, wherein the pad support material is elongated in a longitudinal direction, and wherein the nozzle is positioned over the support device to spray the discrete texture elements at least partially in the longitudinal direction, wherein the support material is elongated in a longitudinal direction and the nozzle is a first nozzle, and wherein the apparatus further comprises a second nozzle in fluid communication with the vessel, the second nozzle being positioned over the support device and offset in the longitudinal direction and in a lateral direction transverse to the longitudinal direction relative to the first nozzle.
- 79. (Previously Presented) An apparatus for forming a planarizing pad for mechanically and/or chemically-mechanically planarizing a microelectronic substrate, the apparatus comprising:
 - a support device configured to support a pad support material in a selected position, wherein the support device includes first and second rollers coupled to the support material and rotatable relative to each other to advance the support material from the first roller to the second roller;
 - a vessel for mixing a planarizing pad material;
 - a nozzle in fluid communication with the vessel and configured to form the planarizing pad material into discrete texture elements for disposing on the support material, wherein the pad support material is elongated in a longitudinal direction, and wherein the nozzle is positioned over the support device to spray the discrete texture elements at least partially in the longitudinal direction;
 - a manifold coupled to the vessel;
 - a first spraybar coupled to the manifold and extending over the support material in transverse direction when the support material is supported by the support device, the first nozzle being connected to the first spraybar; and

- a second spraybar coupled to the manifold and spaced apart from the first spraybar in the longitudinal direction, the second spraybar extending transversely over the support material when the support material is supported by the support device, the second nozzle being connected to the second spraybar.
- 80. (Previously Presented) The apparatus of claim 75, further comprising a heating element positioned proximate to the support device and proximate to the pad support material when the pad support material is supported by the support device.
- 81. (Previously Presented) The apparatus of claim 75, further comprising a grate between the nozzle and the support device, the grate having a plurality of apertures sized to pass the discrete texture elements therethrough.
 - 82. (Canceled).
- 83. (Previously Presented) The apparatus of claim 75 wherein the vessel is a first vessel, and wherein the apparatus further comprises:
 - a second vessel positioned proximate to the second opening, the second vessel configured to contain the discrete texture elements and a film material.

Remar	ks
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The foregoing claim amendments	are provided for discussion purposes only i
a telephone interview scheduled for	p.m. Eastern time between the Examiner
and the attorney identified below.	•
	Respectfully submitted,
	Perkins Coie LLP
Date:	
	Chen Liang
	Registration No. 51,945

Correspondence Address:

Customer No. 25096
Perkins Coie LLP
P.O. Box 1247
Seattle, Washington 98111-1247
(206) 359-8000